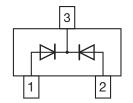


Vishay Semiconductors

RF PIN Diodes - Dual, Common Cathode in SOT-323





DESIGN SUPPORT TOOLS click logo to get started



DESCRIPTION

Characterized by low reverse capacitance the PIN diodes BAR64V-05W was designed for RF signal switching and tuning. As a function of the forward bias current the forward resistance (RF) can be adjusted over a wide range. A long carrier life time offers low signal distortion for signals over 10 MHz up to 3 GHz. Typical applications for these PIN diodes are switches and attenuators in wireless, mobile, and TV-systems.

FEATURES

- High voltage current controlled RF resistor
- Small diode capacitance
- · Low series inductance
- · Low forward resistance
- Improved performance due to two separate dice
- Base P/N-E3 RoHS-compliant, commercial grade
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- For frequencies up to 3 GHz
- · RF-signal tuning
- · Signal attenuator and switches
- Mobile, wireless, and TV-applications

MECHANICAL DATA

Case: SOT-323

Weight: approx. 5.7 mg
Packaging codes/options:

18/10K per 13" reel (8 mm tape), 10K/box 08/3K per 7" reel (8 mm tape), 15K/box

PARTS TABLE						
PART	ART ORDERING CODE		TYPE MARKING CIRCUIT CONFIGURATION			
BAR64V-05W	BAR64V-05W-E3-08 or BAR64V-05W-E3-18	DW5	Common cathode	Tape and reel		

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PART	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V_R	100	V	
Forward continuous current		I _F	100	mA	

THERMAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-55 to +150	°C	
Operating temperature range		T _{op}	-55 to +125	°C	



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ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I _F = 50 mA		V_{F}			1.1	V
Reverse voltage	I _F = 10 μA		V_R	100			V
Reverse current	V _R = 50 V		I _R			0.05	μA
	f = 1 MHz, V _R = 0 V		C_D		0.5		pF
Diode capacitance	f = 1 MHz, V _R = 1 V		C_D		0.37	0.5	pF
	f = 1 MHz, V _R = 20 V		C_D		0.23	0.35	pF
	f = 100 MHz, I _F = 1 mA		r _f		10	20	Ω
Differential forward resistance	f = 100 MHz, I _F = 10 mA		r _f		2	3.8	Ω
	f = 100 MHz, I _F = 100 mA		r _f		0.8	1.35	Ω
Charge carrier lifetime	$I_F = 10 \text{ mA}, I_R = 6 \text{ mA}, I_R = 3 \text{ mA}$		t _{rr}		1.8		μs
Series inductance			L _S		1		nH

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

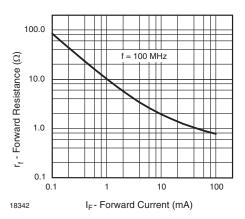


Fig. 1 - Forward Resistance vs. Forward Current

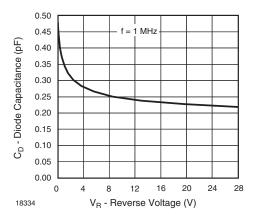


Fig. 2 - Diode Capacitance vs. Reverse Voltage

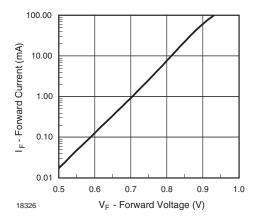


Fig. 3 - Forward Current vs. Forward Voltage

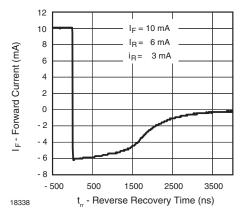


Fig. 4 - Typical Charge Recovery Curve

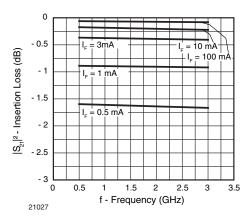


Fig. 5 - Insertion Loss of One Diode Inserted in Series with 50 Ω Strip Line

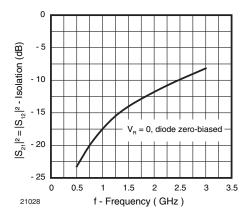


Fig. 6 - Isolation of One Diode Inserted in Series with 50 Ω Strip Line

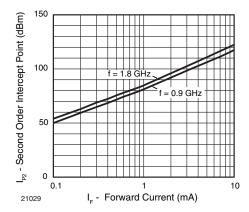
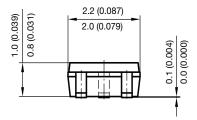
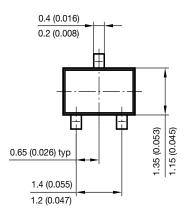


Fig. 7 - Second Order Intercept Point for One Diode Inserted in 50 Ω Strip Line

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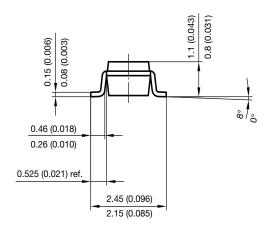
PACKAGE DIMENSIONS in millimeters (inches): SOT-323



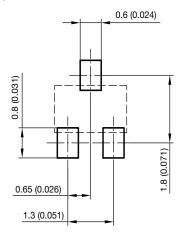


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